Vishay Semiconductors



Standard Recovery Diodes,
(Stud Version), 70 A



DO-5 (DO-203AB)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	70 A			
Package	DO-5 (DO-203AB)			
Circuit configuration	Single			

FEATURES

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V_{RRM}
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Battery charges

MAJOR RATINGS AND CHARACTERISTICS				
DADAMETER	TEST CONDITIONS	70H		
PARAMETER	TEST CONDITIONS	10 TO 120	140/160	UNITS
1		70	70	А
I _{F(AV)}	T _C	140	110	°C
I _{F(RMS)}		110	110	А
I _{FSM}	50 Hz	1200	1200	А
	60 Hz	1250	1250	A
l ² t	50 Hz	7100	7100	A ² s
141	60 Hz	6450	6450	A-S
V _{RRM}	Range	100 to 1200	1400 to 1600	V
TJ		-65 to +180	-65 to +150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{R(BR)} , MINIMUM AVALANCHE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM MA	
	10	100	200	200		
	20	200	300	300	15	
	30	300	400	400	15	
	40	400	500	500		
VS-70HF(R)	60	600	720	725		
V3-70HF(N)	80	800	960	950	9	
	100	1000	1200	1150	9	
	120	1200	1440	1350		
	140	1400	1650	1550	4.5	
	160	1600	1900	1750	4.0	

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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		70HF(R)			
FARAIVIETER	STIVIDUL			10 to 120	140/160	UNITS	
Maximum average forward current	I _{F(AV)}	180° condu	ction, half sine	wave	70)	А
at case temperature	'F(AV)			haro	140	110	°C
Maximum RMS forward current	I _{F(RMS)}				11	0	Α
		t = 10 ms	No voltage		1200 1250		A
Maximum peak, one cycle forward,	l	t = 8.3 ms	reapplied				
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM} reapplied	Sinusoidal half wave, initial T _J = T _J maximum	1000		
		t = 8.3 ms			105	50	
	l ² t	t = 10 ms	No voltage reapplied		7100		A ² s
Maximum I ² t for fusing		t = 8.3 ms			6450 5000		
Maximum -t for fusing		t = 10 ms	100 % V _{RRM}				
		t = 8.3 ms	reapplied		455	4550	
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied			71 0	00	A²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J = T _J maximum		um 0.79		V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		1.00			
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum 2.33		3	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 1.53		3	
Maximum forward voltage drop	V _{FM}	I _{pk} = 220 A,	T _J = 25 °C, t _p =	400 µs rectangular wave	1.35	1.46	V

THERMAL AND MECHANICAL SPECIFICATIONS					
	ARAMETER SYMBOL TEST CONDITIONS	TEST CONDITIONS	70H		
PARAMETER		10 to 120	140/160	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65 to +180	-65 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation		0.45	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
		Not lubricated thread, tighting on nut ⁽¹⁾	3.4	(30)	
Maximum allowable mounting torque (+0 %, -10 %)		Lubricated thread, tighting on nut ⁽¹⁾	2.3 (20)		N⋅m
		Not lubricated thread, tighting on hexagon ⁽²⁾	4.2	(37)	(lbf \cdot in)
		Lubricated thread, tighting on hexagon ⁽²⁾	3.2	(28)	
Approving to weight			1	7	g
Approximate weight			0	.6	oz.
Case style		See dimensions - link at the end of datasheet	DO-	5 (DO-203AB)

Notes

⁽¹⁾ Recommended for pass-through holes

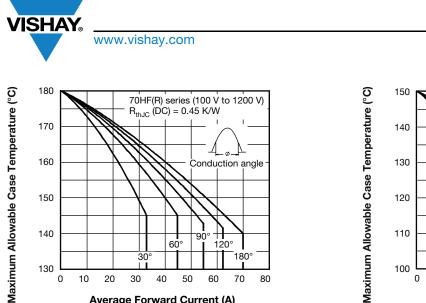
⁽²⁾ Recommended for holed threaded heatsinks

$\Delta \mathbf{R}_{\text{thJC}}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.08	0.06		
120°	0.10	0.11		
90°	0.13	0.14	$T_J = T_J$ maximum	K/W
60°	0.19	0.20		
30°	0.30	0.30		

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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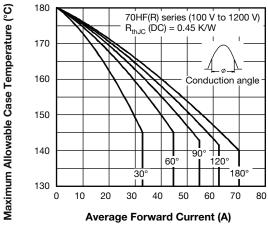


Fig. 1 - Current Ratings Characteristics

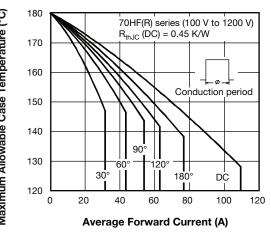


Fig. 2 - Current Ratings Characteristics

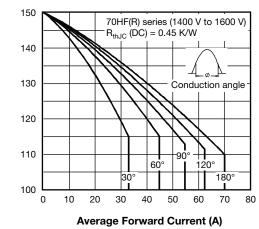


Fig. 3 - Current Ratings Characteristics

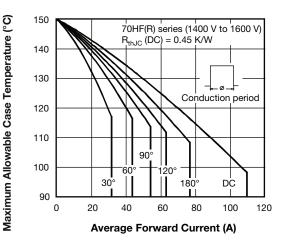
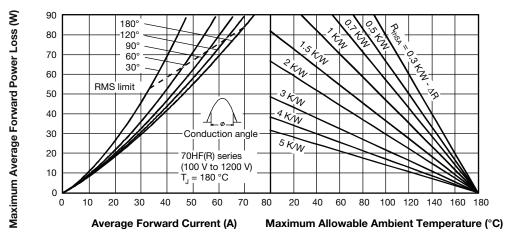
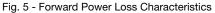


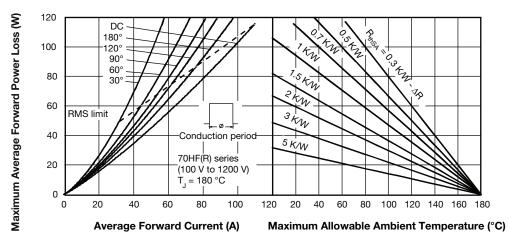
Fig. 4 - Current Ratings Characteristics





Maximum Allowable Case Temperature (°C)

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Fig. 6 - Forward Power Loss Characteristics

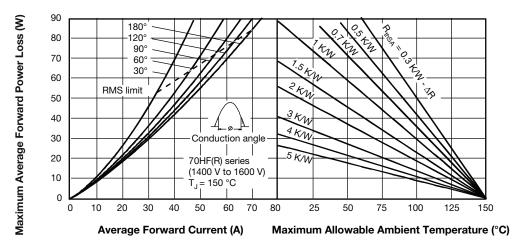
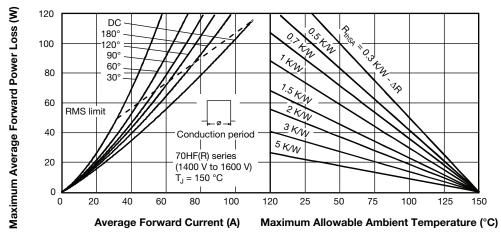
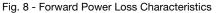


Fig. 7 - Forward Power Loss Characteristics







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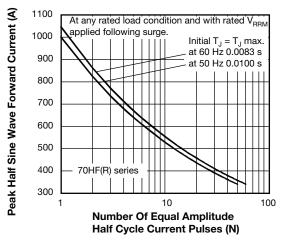


Fig. 9 - Maximum Non-Repetitive Surge Current

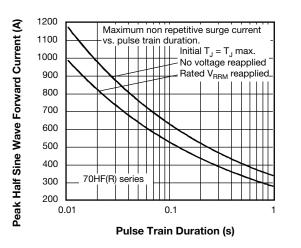


Fig. 10 - Maximum Non-Repetitive Surge Current

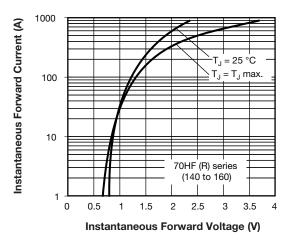
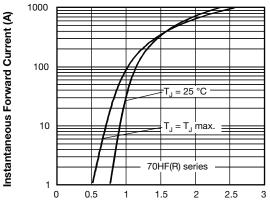


Fig. 13 - Forward Voltage Drop Characteristics



Instantaneous Forward Voltage (V)

Fig. 11 - Forward Voltage Drop Characteristics

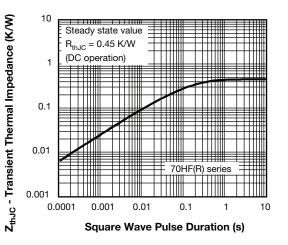


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

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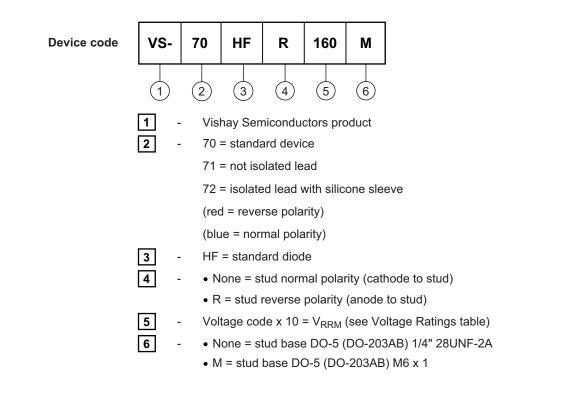
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ORDERING INFORMATION TABLE



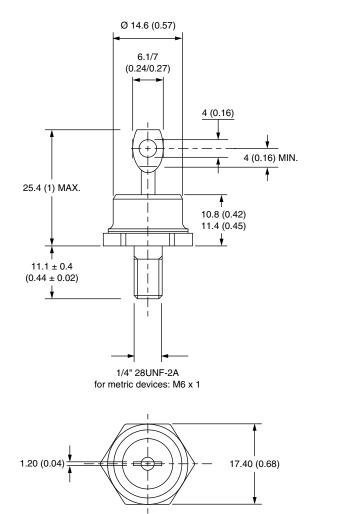
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95343			

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DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series

DIMENSIONS FOR 70HF(R) SERIES in millimeters (inches)

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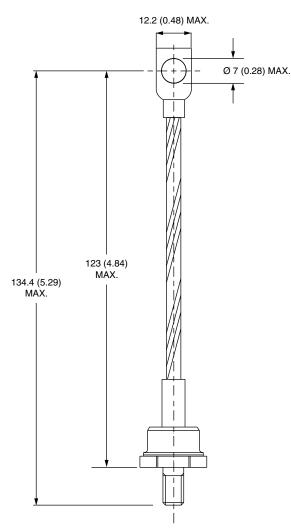


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DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series



DIMENSIONS FOR 71HF(R) SERIES in millimeters (inches)





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